1N5820 THRU 1N5822

Features

- Low Switching Noise
- Low Forward Voltage Drop
- High Current Capability
- High Surge Current Capability

Maximum Ratings

- Operating Temperature: -55°C to +125°C
- Storage Temperature: -55°C to +125°C
- Maximum Thermal Resistance; 28 °C/W Junction To Ambient

	Device	Maximum	Maximum	Maximum
Catalog	Marking	Recurrent	RMS	DC
Number		Peak	Voltage	Blocking
		Reverse		Voltage
		Voltage		
1N5820		20V	14V	20V
1N5821		30V	21V	30V
1N5822		40V	28V	40V

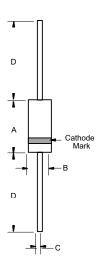
Electrical Characteristics @ 25°C Unless Otherwise Specified

Average Forward Current	I _{F(AV)}	3.0A	T _A = 85°C
Peak Forward Surge	FSM	80A	8.3ms, half sine
Current			
Maximum			
Instantaneous			
Forward Voltage			
1N5820	V_{F}	.475V	$I_{FM} = 3.0A;$
1N5821		.500V	T _J = 25°C*
1N5822		.525V	
Maximum DC			
Reverse Current At	R	2.0mA	T _J = 25°C
Rated DC Blocking		20mA	$T_{\rm J} = 100^{\circ}{\rm C}$
Voltage			
Typical Junction	C _J	200pF	Measured at
Capacitance			1.0MHz, V _R =4.0V

^{*}Pulse test: Pulse width 300 usec, Duty cycle 1%

3 Amp Schottky Barrier Rectifier 20 - 40 Volts

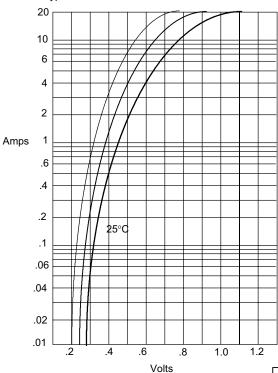


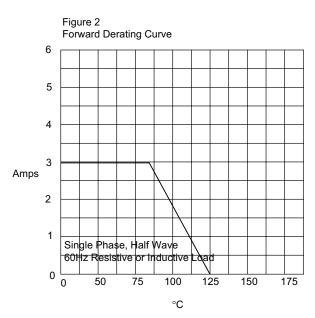


DIMENSIONS							
	INCHES		MM				
DIM	MIN	MAX	MIN	MAX	NOTE		
A		.370		9.50			
В		.250		6.40			
С	.048	.052	1.20	1.30			
D	1.000		25.40				

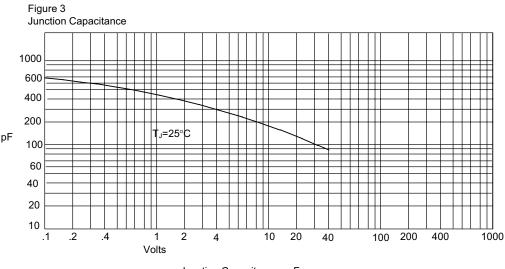
1N5820 thru 1N5822

Figure 1 Typical Forward Characteristics





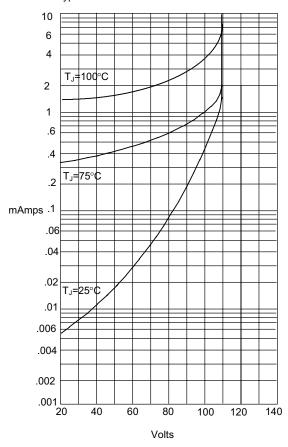
Instantaneous Forward Current - Amperesversus Instantaneous Forward Voltage - Volts



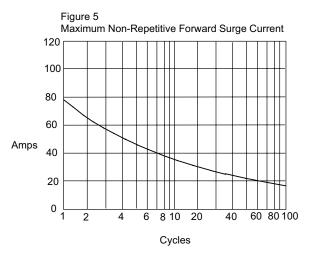
Junction Capacitance - pF*versus* Reverse Voltage - Volts

1N5820 thru 1N5822

Figure 4 Typical Reverse Characteristics



Instantaneous Reverse Leakage Current - MicroAmperesersus Percent Of Rated Peak Reverse Voltage - Volts



Peak Forward Surge Current - Amperesversus Number Of Cycles At 60Hz - Cycles